

Simul	aled is	o-Line Pair	Feature		Rinse	Resist
Space/ node (nm)	Surface Tension (mN/m)	Aspect Ratio (Height) (to find CARC)	SWA (deg)	Top Round (0 = Square Profile, 5 = Rounded Profile)	CA (deg)	Young Moduli (Gpa)
						0.35,
32	72		87,90	5,0	55,75	0.65
		Darametrically				0.245,
22	72	hased on feature	87,90	5, 0	55,75	0.455
		width				0.172,
16	72		87,90	5,0	55,75	0.32
						0.12,
11	72		87,90	5,0	55,75	0.225
Parameter Value		Value	 A parametric finite element study of DI Water drying was 			
CL Position		95% of Height				
Modulus Distribution		Uniform	understand the extendibility			
Poisson		0.4	of simple rinse drying, as well			
			as the	relative pa	aramete	er





sensitivities to collapse

Modeling Line Pattern Collapse Using Finite Element Methods



rinse properties (CA, surface tension) obviously play big role

 Nature of feature shape (SWA, amount of top rounding) also plays an important role

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Two separate effects from surface tension:

- Laplace pressure,
- Force at the contact
- F_{v} is force applied along feature surface and assumed to be nonfactor in analytical

0 -40 -30 -20 -10 0 10 20 30 40 Parameters:

- of a feature can be derived using the Euler beam or Kirchhoff plate theory.
- It is a fourth-order displacement of the feature as a function of external forces and flexural rigidity of the feature.
- If the flexural rigidity is constant, then an analytical solution to the equation can be found.







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